

UNIVERSITY OF MADRAS
M.Sc. DEGREE PROGRAMME IN PHYSICS
 SYLLABUS WITH EFFECT FROM 2023-2024

Elective - List 1 – CRYSTAL GROWTH AND THIN FILMS	I YEAR – FIRST SEMESTER
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Subject Code	Subject Name	Category	L	T	P	Credits	Inst. Hours	Marks
429E1A	CRYSTAL GROWTH AND THIN FILMS	ELECTIVE				3	4	75

Pre-Requisites
Fundamentals of Crystal Physics
Learning Objectives
<ul style="list-style-type: none"> ➤ To acquire the knowledge on Nucleation and Kinetics of crystal growth ➤ To understand the Crystallization Principles and Growth techniques ➤ To study various methods of Crystal growth techniques ➤ To understand the thin film deposition methods ➤ To apply the techniques of Thin Film Formation and thickness Measurement

UNITS	Course Details
UNIT I: CRYSTAL GROWTH KINETICS	Basic Concepts, Nucleation and Kinetics of growth Ambient phase equilibrium - super saturation - equilibrium of finite phases equation of Thomson - Gibbs - Types of Nucleation - Formation of critical Nucleus - Classical theory of Nucleation - Homo and heterogeneous formation of 3D nuclei - rate of Nucleation - Growth from vapour phase solutions, solutions and melts - epitaxial growth - Growth mechanism and classification - Kinetics of growth of epitaxial films
UNIT II: CRYSTALLIZATION PRINCIPLES	Crystallization Principles and Growth techniques Classes of Crystal system - Crystal symmetry - Solvents and solutions - Solubility diagram - Super solubility - expression for super saturation - Metastable zone and introduction period - Miers TC diagram - Solution growth - Low and high temperatures solution growth - Slow cooling and solvent evaporation methods - Constant temperature bath as a Crystallizer.

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UNIT III: GEL, MELT AND VAPOUR GROWTH	Gel, Melt and Vapour growth techniques Principle of Gel techniques - Various types of Gel - Structure and importance of Gel - Methods of Gel growth and advantages - Melt techniques - Czochralski growth - Floating zone - Bridgeman method - Horizontal gradient freeze - Flux growth - Hydrothermal growth - Vapour phase growth - Physical vapour deposition - Chemical vapour deposition - Stoichiometry.
UNIT IV: THIN FILM DEPOSITION METHODS	Thin film deposition methods of thin film preparation, Thermal evaporation, Electron beam evaporation, pulsed LASER deposition, Cathodic sputtering, RF Magnetron sputtering, MBE, chemical vapour deposition methods, Sol Gel spin coating, Spray pyrolysis, Chemical bath deposition.

UNIT V: THIN FILM FORMATION	Thin Film Formation and thickness Measurement Nucleation, Film growth and structure - Various stages in Thin Film formation, Thermodynamics of Nucleation, Nucleation theories, Capillarity model and Atomistic model and their comparison. Structure of Thin Film, Roll of substrate, Roll of film thickness, Film thickness measurement - Interferometry, Ellipsometry, Micro balance, Quartz Crystal Oscillator techniques.
UNIT VI: PROFESSIONAL COMPONENTS	Expert Lectures, Online Seminars - Webinars on Industrial Interactions/Visits, Competitive Examinations, Employable and Communication Skill Enhancement, Social Accountability and Patriotism
TEXT BOOKS	<ol style="list-style-type: none"> 1. V. Markov Crystal growth for beginners: Fundamentals of Nucleation, Crystal Growth and Epitaxy (2004) 2nd edition 2. A. Goswami, Thin Film Fundamentals (New Age, New Delhi, 2008) 3. M. Ohora and R. C. Reid, "Modeling of Crystal Growth Rates from Solution" 4. D. Elwell and H. J. Scheel, "Crystal Growth from High Temperature Solution" 5. Heinz K. Henish, 1973, "Crystal Growth in Gels", Cambridge University Press. USA.
REFERENCE BOOKS	<ol style="list-style-type: none"> 1. J.C. Brice, Crystal Growth Process (John Wiley, New York, 1986) 2. P. Ramasamy and F. D. Gnanam, 1983, "UGC Summer School Notes". 3. P. SanthanaRaghavan and P. Ramasamy, "Crystal Growth Processes", KRU Publications. 4. H.E. Buckley, 1951, Crystal Growth, John Wiley and Sons, New York 5. B.R. Pamplin, 1980, Crystal Growth, Pergman Press, London.

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WEB SOURCES	<ol style="list-style-type: none"> https://www.youtube.com/playlist?list=PLbMVogVj5nJRjLrXp3kMtrlO8kZI1D1Jp https://www.youtube.com/playlist?list=PLFW6lRTa1g83HGEihgwy7KeTLUuBu3WF https://www.youtube.com/playlist?list=PLADLRin7kNjG1Dlna9MDA53CMKFHPSi9m https://www.youtube.com/playlist?list=PLXHedI-xbyr8xII_KQFs_R_oky3Yd1Emw https://www.electrical4u.com/thermal-conductivity-of-metals/
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COURSE OUTCOMES:

At the end of the course, the student will be able to:

CO1	Acquire the Basic Concepts, Nucleation and Kinetics of crystal growth	K1
CO2	Understand the Crystallization Principles and Growth techniques	K2, K4
CO3	Study various methods of Crystal growth techniques	K3
CO4	Understand the Thin film deposition methods	K2
CO5	Apply the techniques of Thin Film Formation and thickness Measurement	K3, K4
K1 - Remember; K2 – Understand; K3 - Apply; K4 - Analyze; K5 - Evaluate;		

MAPPING WITH PROGRAM OUTCOMES:

Map course outcomes (CO) for each course with program outcomes (PO) and program specific outcomes (PSO) in the 3-point scale of STRONG (3), MEDIUM (2) and LOW (1).

	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10
CO1	3	2	1	2	1	3	2	2	2	2
CO2	3	3	1	3	1	2	3	2	2	1
CO3	3	2	1	3	1	2	3	3	3	1
CO4	3	2	1	2	1	2	3	3	3	1
CO5	2	3	3	3	1	3	3	3	3	2

	PSO1	PSO2	PSO3	PSO4	PSO5	PSO6	PSO7	PSO8	PSO9	PSO10
CO1	3	2	1	2	1	3	2	2	2	2
CO2	3	3	1	3	1	2	3	2	2	1
CO3	3	2	1	3	1	2	3	3	3	1
CO4	3	2	1	2	1	2	3	3	3	1
CO5	2	3	3	3	1	3	3	3	3	2